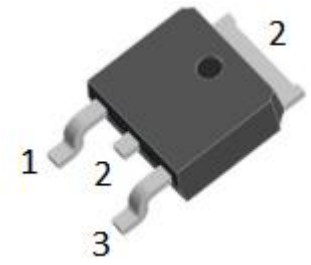
Technical Data
Data Sheet N0604, Rev. A

6CWQ03FN SCHOTTKY RECTIFIER

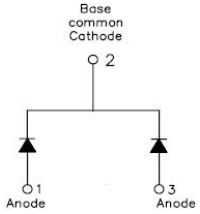


DPAK

Features

- 150℃ T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb − Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	30	V
Average Rectified Forward Current	$I_{F\ (AV)}$	50% duty cycle @T_C = 131°C, rectangular wave form	3.5(Peg Leg) 7(Peg Device)	A
Peak One Cycle Non-Repetitive Surge Current(Peg Leg)	I_{FSM}	8.3 ms, half Sine pulse	108	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop (Per Leg) *	V_{F1}	@ 3A, Pulse, T_J = 25 °C @ 6A, Pulse, T_J = 25 °C	0.42 -	0.45 0.52	V
	V_{F2}	@ 3A, Pulse, T_J = 125 °C @ 6A, Pulse, T_J = 125 °C	0.32 -	0.35 0.46	V
Reverse Current (per leg) *	I_{R1}	@V_R = rated V_R , T_J = 25 °C	0.02	1.00	mA
	I_{R2}	@V_R = rated V_R, T_J = 125 °C	17	50	mA
Junction Capacitance(Per Leg)	C_T	@V_R = 5V, T_C = 25 °C, f_{SIG} = 1MHz	200	290	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 μs, duty cycle < 2%

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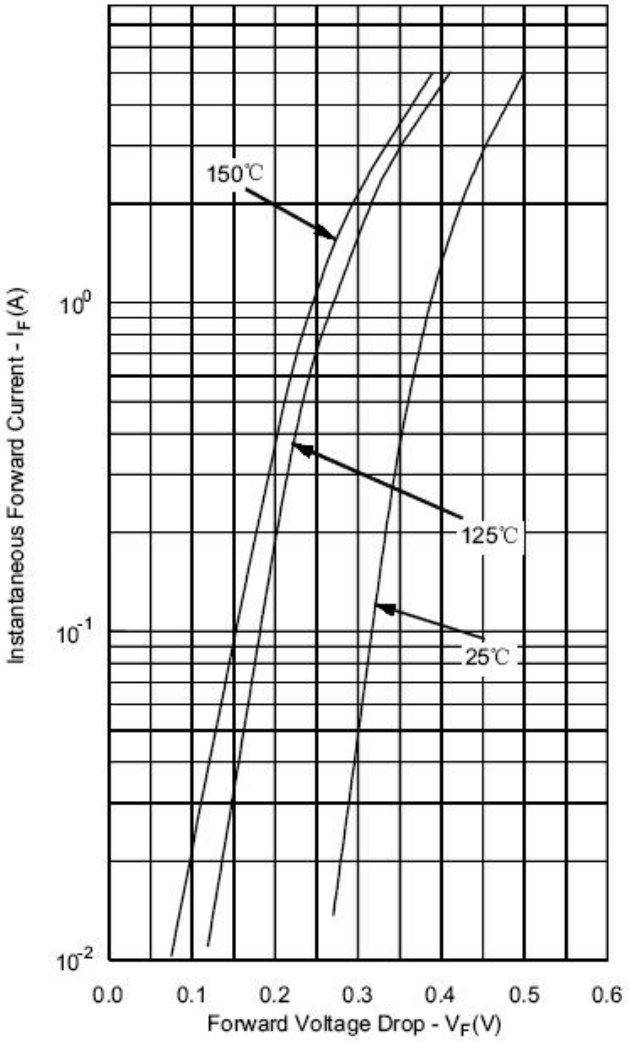
RoHS

Thermal-Mechanical Specifications:

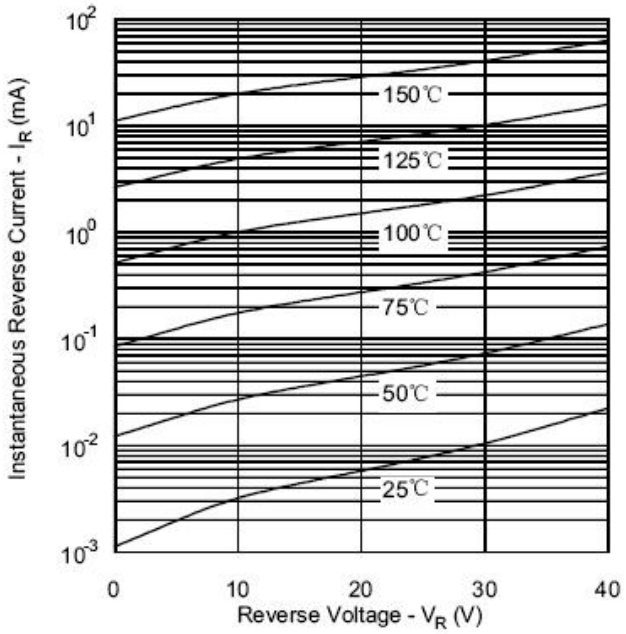
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{\theta JC}$	-	4.7(peg leg) 2.35(peg device)	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

Ratings and Characteristics Curves

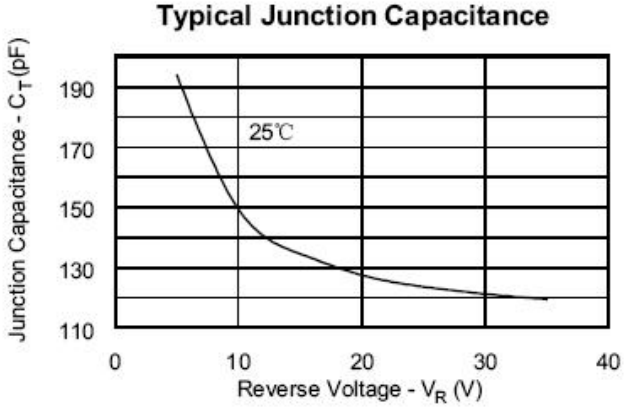
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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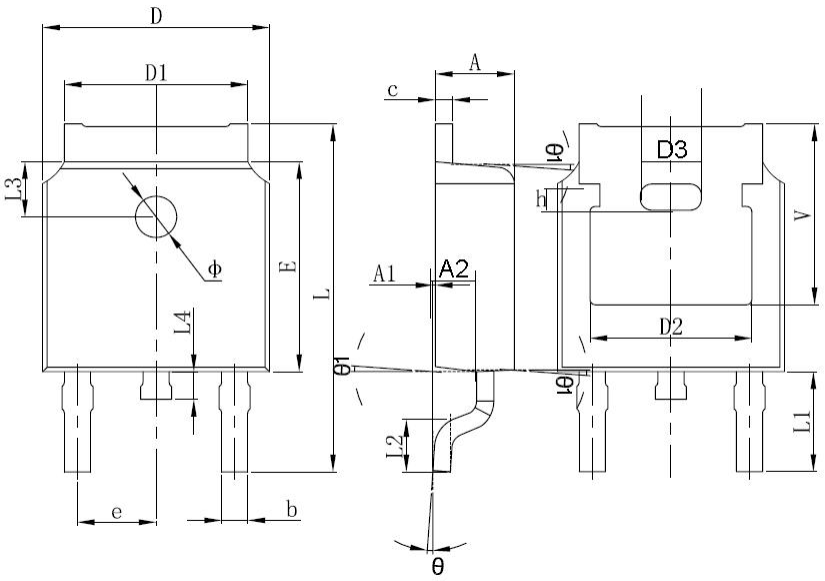
Mechanical Dimensions DPAK



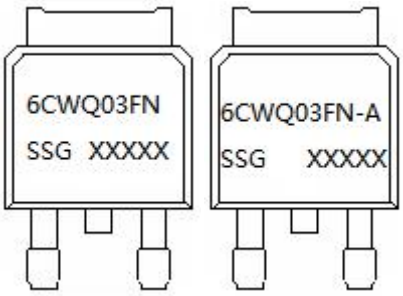
SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.40	0.087	0.094
A1	0.00	0.127	0.000	0.005
b	0.66	0.86	0.026	0.034
c	0.46	0.60	0.018	0.024
D	6.50	6.70	0.256	0.264
D1	5.13	5.46	0.202	0.215
D2	4.83 REF.		0.190 REF.	
E	6.00	6.20	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.70	10.40	0.381	0.409
L1	2.90 REF.		0.144 REF.	
L2	1.40	1.70	0.055	0.067
L3	1.60 REF.		0.063 REF.	
L4	0.60	1.00	0.024	0.039
Φ	1.10	1.30	0.043	0.051
Θ	0°	8°	0°	8°
h	0.00	0.30	0.000	0.012
V	5.35 REF.		0.211 REF.	

Ordering Information

Device	Package	Shipping
6CWQ03FN	DPAK (Pb-Free)	2500pcs / reel
6CWQ03FNTR	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

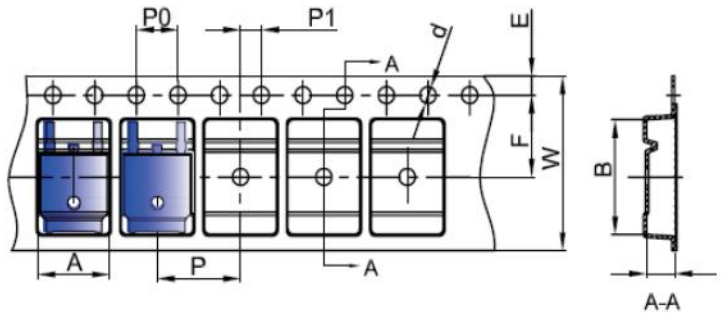


Where XXXXX is YYWWL

6	= Forward Current (7A)
CW	= Configuration
Q	= Device Type
03	= Reverse Voltage (30V)
FN	= Package type
-A	= AEC-Q101
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters	
	Min.	Max.
A	6.80	7.00
B	10.40	10.60
C	2.60	2.80
d	Φ1.45	Φ1.65
E	1.65	1.85
F	7.40	7.60
P0	3.90	4.10
P	7.90	8.10
P1	1.90	2.10
W	15.90	16.30

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